

VHF Variable Capacitance Diode

FEATURES

- High linearity
- Excellent matching to 1% DMA
- · Very small plastic SMD package
- C28: 2.5 pF; ratio: 26.

APPLICATIONS

- Electronic tuning in VHF television tuners, band A up to 160 MHz
- · VCO.

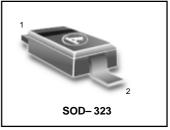
DESCRIPTION

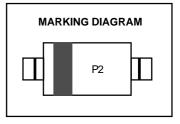
The BB132 is a variable capacitance diode fabricated in planar technology, and encapsulated in the SOD323 very small plastic SMD package.

The excellent matching performance is achieved by gliding matching and a direct matching assembly procedure.



BB132





LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	L PARAMETER		MAX.	UNIT	
V _R	continuous reverse voltage	-	30	V	
I _F	continuous forward current	-	20	mA	
T _{stg}	storage temperature	-55	+150	°C	
Tj	operating junction temperature	-55	+125	°C	

ELECTRICAL CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
lr	reverse current	VR = 30 V; see Fig.2		10	nA
		$V_{R} = 30 V; T_{j} = 85 °C; see Fig.2$	-	200	nA
ľs	diode series resistance	f = 100 MHz; note 1		2	Ω
Cd	diode capacitance	$V_R = 0.5 V$; f = 1 MHz; see Figs 1 and 3	60	75	рF
		VR = 28 V;f = 1 MHz; see Figs 1 and 3	2.3	2.75	рF
Cd(0.5V) Cd (28V)	capacitance ratio	f = 1 MHz	24	30	
ΔC d	capacitance matching	V _R = 0.5 to 28 V; in a sequence of 4 diodes (gliding)	-	1	%
Cd		V _R = 0.5 to 28 V; in a sequence of 15 diodes (gliding)	_	2	%

Note

1. VR is the value at which Cd = 30 pF.





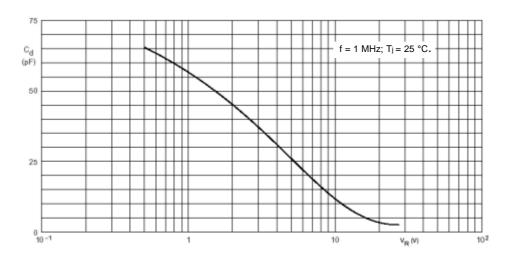


Fig.1 Diode capacitance as a function of reverse voltage; typical values.

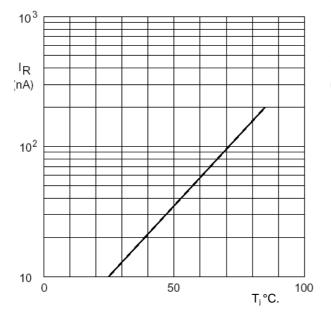


Fig.2 Reverse current as a function of junction temperature; maximum values.

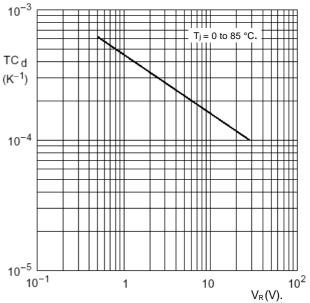


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.